CompactFlash cards

1 General information

CompactFlash cards are easily replaceable storage media. Due to their robustness against environmental influences (temperature, shock, vibration, etc.), CompactFlash cards are ideal for use as storage medium in industrial environments.

2 Basic information

CompactFlash cards used in industrial automation must be extremely reliable. To achieve this, the following points are very important:

- The flash technology used
- · An efficient algorithm for maximizing service life
- · Good mechanisms for detecting and correcting errors in the flash memory

2.1 Flash technology

CompactFlash cards are currently available with MLC (multi-level cell) and SLC (single-level cell) flash blocks. SLC flash memory has a guaranteed service life 10 times longer than MLC flash memory, which means that only CompactFlash cards with SLC flash blocks are used for industrial applications.

2.2 Wear leveling

Wear leveling refers to an algorithm that can be used to maximize the service life of a CompactFlash. Different algorithms are possible:

- No wear leveling
- Dynamic wear leveling
- Static wear leveling

The basic idea behind wear leveling is that data is distributed over a broad range of blocks or cells on the data storage medium so that the same areas are not erased and rewritten over and over again.

2.2.1 No wear leveling

The earliest CompactFlash cards did not have algorithms for maximizing service life. The service life of a CompactFlash card was determined only by the guaranteed lifespan of the flash blocks.

2.2.2 Dynamic wear leveling

Dynamic wear leveling makes it possible to utilize unused flash blocks when writing to a file. If 80% of the data storage medium is already taken up by files, then only 20% can be used for wear leveling. The service life of the CompactFlash therefore depends on the unused flash blocks.

2.2.3 Static wear leveling

Static wear leveling additionally monitors which data is only seldom modified. From time to time, the controller moves this data to blocks that have already been written to frequently in order to prevent further wear on those cells.

2.3 ECC error correction

Bit errors can result from the inactivity or operation of a certain cell. Error-correcting code (ECC) added by the hardware or software can detect and correct many errors of this type.

2.4 S.M.A.R.T. support

Self-Monitoring, Analysis and Reporting Technology (S.M.A.R.T.) is an industry standard for mass storage devices that was introduced to monitor important parameters and detect imminent failures. Critical performance and calibration data is monitored and stored in an effort to predict the probability of error states.

2.5 Maximum reliability

CompactFlash cards supplied by B&R use SLC flash blocks and static wear leveling in combination with a powerful ECC algorithm to provide maximum reliability.

3 Dimensions



Figure 1: CompactFlash card type I dimensions

4 0CFCRD.xxxxE.01

4.1 General information

Information:

On Windows CE 5.0 devices, 0CFCRD.xxxxE.01 CompactFlash cards up to 1 GB are supported.

4.2 Order data

Model number	Short description	Figure
	CompactFlash cards	
0CFCRD.0512E.01	CompactFlash 512 MB extended temp.	
0CFCRD.2048E.01	CompactFlash 2048 MB extended temp.	Suissbit* 512MB Industrial CompactFlashCard

Table 1: 0CFCRD.0512E.01, 0CFCRD.2048E.01 - Order data

4.3 Technical data

Caution!

A sudden power failure may result in data loss! In very rare cases, the mass storage device may also become damaged.

In order to prevent data loss or damage, B&R recommends the use of a UPS.

Information:

The following specifications, properties and limit values apply only to this accessory and may deviate from those that apply to the complete system. For the complete system in which this accessory is installed, the data specified for that complete system applies.

Model number	0CFCRD.0512E.01 0CFCRD.2048E.01			
General information				
Capacity	512 MB	2048 MB		
Data retention	10 y	ears		
Data reliability	<1 unrecoverable er	ror per 10 ¹⁴ bits read		
Lifetime monitoring	Y	es		
MTBF	>3,000,000 h	ours (at 40°C)		
Maintenance	Nc	ne		
Supported operating modes	PIO mode 0-6, Multiword DMA mode 0-4, Ultra DMA Mode 0-4			
Sequential read				
Typical	58 MB/s			
Maximum	65 MB/s			
Sequential write				
Typical	31 MB/s			
Maximum	35 MB/s			
Certifications				
CE	Yes			
UL	Not relevant	-		
DNV GL	Temperature: B (0 - 55°C) Humidity: B (up to 100%) Vibration: B (4 g) EMC: B (bridge and open deck)	-		
LR	ENV1	-		

Table 2: 0CFCRD.0512E.01, 0CFCRD.2048E.01 - Technical data

CompactFlash cards

Model number	0CFCRD.0512E.01	0CFCRD.2048E.01				
Endurance						
SLC flash	Ye	28				
Erase/Write cycles						
Guaranteed	100,000					
Wear leveling	Sta	atic				
Error correction coding (ECC)	Ye	es				
S.M.A.R.T. support	Ye	es				
Environmental conditions						
Temperature						
Operation	-40 to	85°C				
Storage	-50 to	100°C				
Transport	-50 to	100°C				
Relative humidity						
Operation	Max. 85%	6 at 85°C				
Storage	Max. 85%	6 at 85°C				
Transport	Max. 85%	6 at 85°C				
Vibration						
Operation	20 g peak, 20 to 2000 Hz, 4 in each direction (JEDEC JESD22, method B103) 5.35 g RMS, 15 min. per level (IEC 68-2-6)					
Storage	20 g peak, 20 to 2000 Hz, 4 in each direction (JEDEC JESD22, method B103) 5.35 g RMS, 15 min. per level (IEC 68-2-6)					
Transport	20 g peak, 20 to 2000 Hz, 4 in each direction (JEDEC JESD22, method B103) 5.35 g RMS, 15 min. per level (IEC 68-2-6)					
Shock						
Operation	1500 g peak, 0.5 ms 5 times (JEDEC JESD22, method B110) 30 g, 11 ms 1 time (IEC 68-2-27)					
Storage	1500 g peak, 0.5 ms 5 times (JEDEC JESD22, method B110) 30 g, 11 ms 1 time (IEC 68-2-27)					
Transport	1500 g peak, 0.5 ms 5 times (J 30 g, 11 ms 1 tim	EDEC JESD22, method B110) ne (IEC 68-2-27)				
Elevation						
Operation	Max. 4,572 m					
Mechanical properties		·				
Dimensions						
Width	42.8 ± 0.10 mm					
Length	36.4 ± 0).15 mm				
Height	3.3 ± 0.	3.3 ± 0.10 mm				
Weight	10 g					

Table 2: 0CFCRD.0512E.01, 0CFCRD.2048E.01 - Technical data

4.4 Temperature/Humidity diagram for operation and storage



Figure 2: 0CFCRD.xxxxE.01 CompactFlash cards - Temperature/Humidity diagram

Diagram legend						
(1)	Operation	T [°C]	Temperature in °C			
(2)	Storage and transport	RH [%]	Relative humidity (RH) in percent and non-condensing			

5 5CFCRD.xxxx-06

5.1 General information

Information:

B&R 5CFCRD.xxxx-06 CompactFlash cards and CompactFlash cards from other manufacturers are not permitted to be used in the same system at the same time. Due to differences in technology (older vs. newer technologies), problems can occur during system startup that are caused by different startup times.

Information:

5CFCRD.xxxx-06 CompactFlash cards are supported on B&R devices with WinCE version \ge 6.0.

5.2 Order data

Model number	Short description	Figure
	CompactFlash cards	
5CFCRD.0512-06	CompactFlash 512 MB B&R (SLC)	and the second s
5CFCRD.1024-06	CompactFlash 1 GB B&R (SLC)	
5CFCRD.2048-06	CompactFlash 2 GB B&R (SLC)	Silicekiu
5CFCRD.4096-06	CompactFlash 4 GB B&R (SLC)	JUISSDIT
5CFCRD.8192-06	CompactFlash 8 GB B&R (SLC)	
5CFCRD.016G-06	CompactFlash 16 GB B&R (SLC)	
5CFCRD.032G-06	CompactFlash 32 GB B&R (SLC)	512MB

Table 3: 5CFCRD.0512-06, 5CFCRD.1024-06, 5CFCRD.2048-06, 5CFCRD.4096-06, 5CFCRD.8192-06, 5CFCRD.016G-06, 5CFCRD.032G-06 - Order data

5.3 Technical data

Caution!

A sudden power failure may result in data loss! In very rare cases, the mass storage device may also become damaged.

To prevent damage and loss of data, the use of a UPS is recommended.

Information:

The following specifications, properties and limit values apply only to this accessory and may deviate from those that apply to the complete system. For the complete system in which this accessory is installed, for example, the data specified for that complete system applies.

Model number	5CFCRD. 0512-06	5CFCRD. 1024-06	5CFCRD. 2048-06	5CFCRD. 4096-06	5CFCRD. 8192-06	5CFCRD. 016G-06	5CFCRD. 032G-06
General information	L	I	I	I			,
Capacity	512 MB	1 GB	2 GB	4 GB	8 GB	16 GB	32 GB
Data retention ¹⁾			Į.	10 years			
Data reliability			<1 unrecove	erable error per 10	014 bits read		
Lifetime monitoring				Yes			
MTBF			>3,00	00,000 hours (at 2	25°C)		
Maintenance			,	None	,		
Supported operating modes		PIO r	node 0-6, Multiwo	ord DMA mode 0-4	4, Ultra DMA Moc	de 0-4	
Sequential read			,		,		-
Typical	50 N	//B/s		59 N	/IB/s		58 MB/s
Maximum	53 N	//B/s			65 MB/s		,
Sequential write		-	l				
Typical	25 N	//B/s			31 MB/s		
Maximum	27 N	//B/s			35 MB/s		
Certifications							
CE				Yes			
UL				cULus E115267			
			Indus	strial control equip	ment		
DNV GL			Tem	perature: A (0 - 4	5°C)		
			Hun	nidity: B (up to 10	0%)		
				/ibration: A (0.7 g)		
			EMC: E	B (bridge and ope	n deck)		
GOST-R				Yes			
Endurance ¹⁾	ſ						
SLC flash				Yes			
Guaranteed data volume							
Guaranteed ²⁾	50 TB	100 TB	200 TB	400 TB	800 TB	1600 TB	3200 TB
Results for 5 years ²⁾	27.40 GB/day	54.79 GB/day	109.59 GB/day	219.18 GB/day	438.36 GB/day	876.72 GB/day	1753.44 GB/day
Erase/Write cycles							
Guaranteed				100,000			
Wear leveling				Static			
Error correction coding (ECC)				Yes			
S.M.A.R.T. support				Yes			
Support							
Hardware		PP300/400, PP50	0, PPC300, PPC	700, PPC725, PP	PC800, APC620, APC60, APC620, APC620, APC620, APC620, APC600, APC600, APC600, APC600, APC600, APC600, APC600, APC600, APC6200, APC600, APC600, APC600, APC600, APC600, APC600, APC600,	APC810, APC820)
Operating systems							
Windows 7 32-bit			No			Y	es
Windows 7 64-bit	No Yes				Yes		
Windows Embedded Standard 7 32-bit	No Yes						
Windows Embedded Standard 7 64-bit	No Yes						
Windows XP Professional	No Yes						
Windows XP Embedded	Yes						
Windows Embedded Standard 2009	No			Ye	es		
Windows CE 6.0	Yes Yes Yes						
Windows CE 5.0				No		1	
Software				-			
PVI Transfer	≥V3.2.3.8 (part of PVI Development Setup ≥ V2.06.00.3011) ≥V3.6.8.40 ≥V4.0.0.8 (part of PV/I Development Setup ≥ V2.06.00.3011)			≥V4.0.0.8 (part of PVI Devel-			
	Develop- opment Setup ment Setup ≥ ≥V3.0.2.3014)						
B&R Embedded OS Installer			≥V3.10			≥V3.20	≥V3.21

Table 4: 5CFCRD.0512-06, 5CFCRD.1024-06, 5CFCRD.2048-06, 5CFCRD.4096-06, 5CFCRD.8192-06, 5CFCRD.016G-06, 5CFCRD.032G-06 - Technical data

CompactFlash cards

Model number	5CFCRD.	5CFCRD.	5CFCRD.	5CFCRD.	5CFCRD.	5CFCRD.	5CFCRD.	
	0512-06	1024-06	2048-06	4096-06	8192-06	016G-06	032G-06	
Environmental conditions								
Temperature								
Operation		0 to 70°C						
Storage				-50 to 100°C			-	
Transport				-50 to 100°C				
Relative humidity					-			
Operation				Max. 85% at 85°	С			
Storage				Max. 85% at 85°	С			
Transport				Max. 85% at 85°	С			
Vibration		-					_	
Operation		20 g peak, 20 to 2000 Hz, 4 in each direction (JEDEC JESD22, method B103)						
Storage		20 g peak, 20 to 2000 Hz, 4 in each direction (JEDEC JESD22, method B103) 5,35 g RMS, 15 min, per level (IEC 68-2-6)						
Transport		20 g peak, 20 to 2000 Hz, 4 in each direction (JEDEC JESD22, method B103) 5.35 g RMS, 15 min. per level (IEC 68-2-6)						
Shock		-		<u>·</u> ·				
Operation		1500 g peak, 0.5 ms 5 times (JEDEC JESD22, method B110) 30 g, 11 ms 1 time (IEC 68-2-27)						
Storage		1500 g peak, 0.5 ms 5 times (JEDEC JESD22, method B110) 30 g, 11 ms 1 time (IEC 68-2-27)						
Transport		1500 g peak, 0.5 ms 5 times (JEDEC JESD22, method B110) 30 g, 11 ms 1 time (IEC 68-2-27)						
Elevation								
Operation		Max. 4,572 m						
Mechanical properties								
Dimensions								
Width				42.8 ± 0.10 mm	1			
Length				36.4 ± 0.15 mm	1			
Height				3.3 ± 0.10 mm				
Weight		10 g						

Table 4: 5CFCRD.0512-06, 5CFCRD.1024-06, 5CFCRD.2048-06, 5CFCRD.4096-06, 5CFCRD.8192-06, 5CFCRD.016G-06, 5CFCRD.032G-06 - Technical data

1) Per JEDEC (JESD47), EOL conditions are not permitted to be reached before 18 months. A higher average daily write workload reduces the expected service life and data retention of the data storage medium.

2) Endurance of B&R CFs (with linear written block size ≥128 kB).

3) Not supported by the B&R Embedded OS Installer.

5.4 Temperature/Humidity diagram



Figure 3: 5CFCRD.xxxx-06 CompactFlash cards - Temperature/Humidity diagram

Diagram legend					
(1)	Operation	T [°C]	Temperature in °C		
(2)	Storage and transport	RH [%]	Relative humidity (RH) in percent and non-condensing		